

Notice of References Cited	Application/Control No.	Applicant(s)/Patent Under Reexamination	
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	Examiner	Art Unit	
	Thomas L. Dickey	2826	Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-			
	B	US-			
	C	US-			
	D	US-			
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FOREIGN PATENT DOCUMENTS

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	N					
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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Shan et al., "Band Anticrossing in GaInNAs Alloys," Phys. Rev. Lett. Vol. 82, No. 6, pp 1221-1224 (1999)
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

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